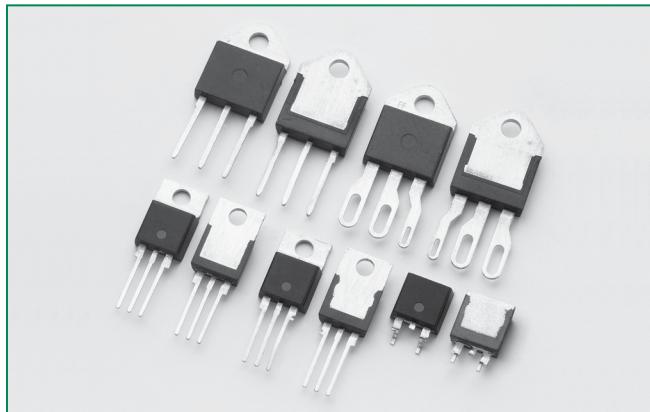


### Sxx55x Series



#### Description

Excellent unidirectional switches for phase control applications such as heating and motor speed controls.

Standard phase control SCRs are triggered with few milliamperes of current at less than 1.5V potential.

#### Features & Benefits

- RoHS-compliant
- Glass – passivated junctions
- Voltage capability up to 1000 V
- Surge capability up to 650 A

#### Main Features

Symbol	Value	Unit
$I_{T(RMS)}$	55	A
$V_{DRM}/V_{RRM}$	400 to 1000	V
$I_{GT}$	40	mA

#### Additional Information



Datasheet



Resources

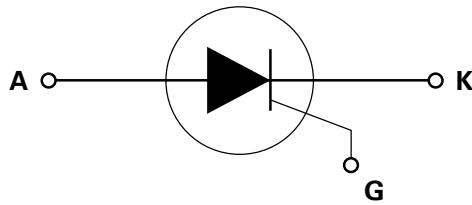


Samples

#### Applications

Typical applications are AC solid-state switches, industrial power tools, exercise equipment, white goods and commercial appliances.

#### Schematic Symbol



#### Absolute Maximum Ratings

Symbol	Parameter	Test Conditions	Value	Unit
$I_{T(RMS)}$	RMS on-state current	$T_c = 90^\circ\text{C}$	55	A
$I_{T(AV)}$	Average on-state current	$T_c = 90^\circ\text{C}$	35.0	A
$I_{TSM}$	Peak non-repetitive surge current	single half cycle; $f = 50\text{Hz}$ ; $T_j$ (initial) = $25^\circ\text{C}$	550	A
		single half cycle; $f = 60\text{Hz}$ ; $T_j$ (initial) = $25^\circ\text{C}$	650	
$I^2t$	$I^2t$ Value for fusing	$t_p = 8.3 \text{ ms}$	1750	$\text{A}^2\text{s}$
$di/dt$	Critical rate of rise of on-state current	$f = 60\text{Hz}; T_j = 125^\circ\text{C}$	175	$\text{A}/\mu\text{s}$
$I_{GM}$	Peak gate current	$T_j = 125^\circ\text{C}$ $P_w = 10\mu\text{S}$	4.0	A
$P_{G(AV)}$	Average gate power dissipation	$T_j = 125^\circ\text{C}$	0.8	W
$T_{stg}$	Storage temperature range		-40 to 150	$^\circ\text{C}$
$T_j$	Operating junction temperature range		-40 to 125	$^\circ\text{C}$

**Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)**

Symbol	Test Conditions		Value	Unit
$I_{GT}$	$V_D = 12\text{V}; R_L = 30 \Omega$	MAX.	40	mA
		MIN.	5	
$V_{GT}$	$V_D = 12\text{V}; R_L = 30 \Omega$	MAX.	1.5	V
$dv/dt$	$V_D = V_{DRM}$ ; gate open; $T_J = 100^\circ\text{C}$	400V	MIN.	V/ $\mu\text{s}$
		600V		
		800V		
		1000V		
	$V_D = V_{DRM}$ ; gate open; $T_J = 125^\circ\text{C}$	400V		
		600V		
		800V		
		475		
$V_{GD}$	$V_D = V_{DRM}; R_L = 3.3 \text{k}\Omega; T_J = 125^\circ\text{C}$	MIN.	0.2	V
$I_H$	$I_T = 400\text{mA}$ (initial)	MAX.	60	mA
$t_a$	(1)	MAX.	35	$\mu\text{s}$
$t_{gt}$	$I_G = 2 \times I_{GT}$ ; PW = 15 $\mu\text{s}$ ; $I_T = 110\text{A}$	TYP.	2.5	$\mu\text{s}$

**Note :**

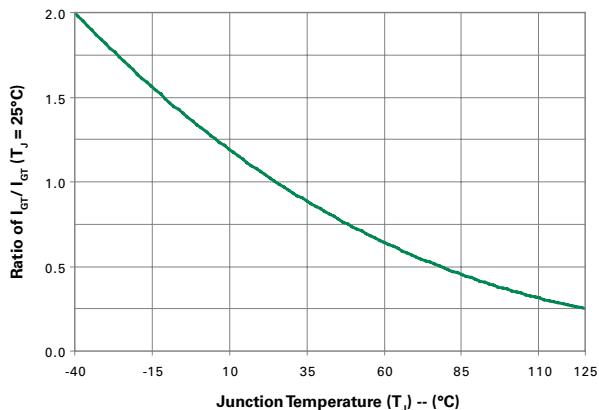
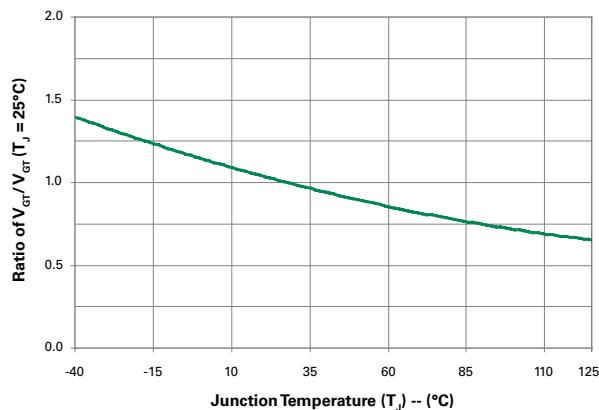
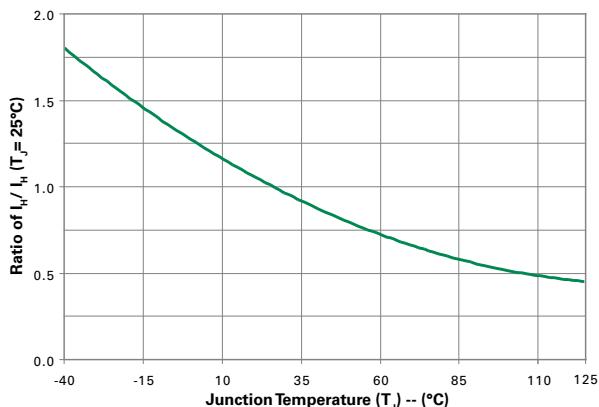
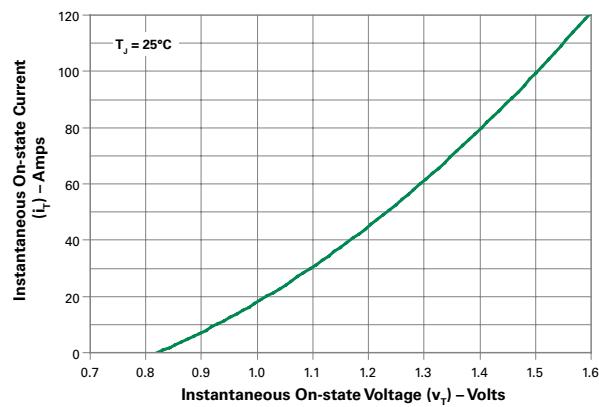
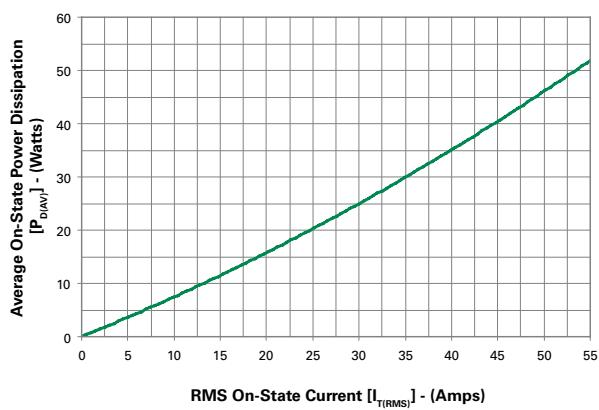
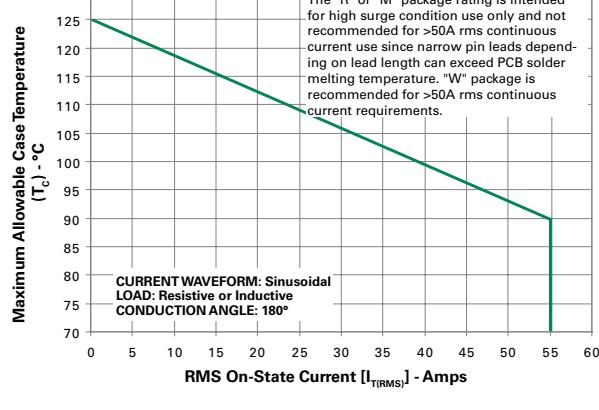
 (1)  $I_T = 2\text{A}$ ;  $t_p = 50\mu\text{s}$ ;  $dv/dt = 5\text{V}/\mu\text{s}$ ;  $di/dt = -30\text{A}/\mu\text{s}$ 
**Static Characteristics**

Symbol	Test Conditions		Value	Unit
$V_{TM}$	$I_T = 110\text{A}; t_p = 380\mu\text{s}$	MAX.	1.8	V
$I_{DRM} / I_{RRM}$	$V_{DRM} / V_{RRM}$	$T_J = 25^\circ\text{C}$	400 – 600V	$\mu\text{A}$
			800V	
			1000V	
		$T_J = 100^\circ\text{C}$	400 – 600V	
			800V	
	$T_J = 125^\circ\text{C}$	1000V	1000	
		400 – 600V	1500	
		800V	5000	
		2000	2000	
		800V	3000	

**Thermal Resistances**

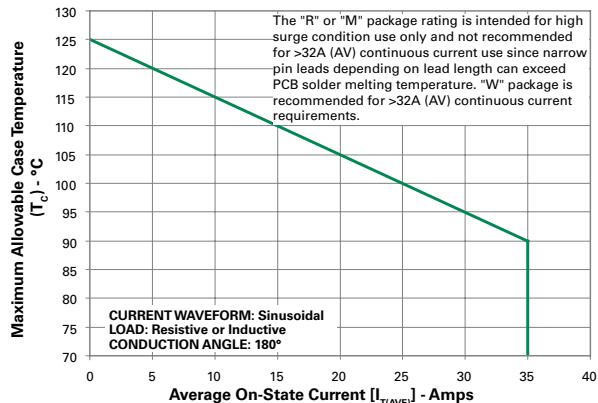
Symbol	Parameter		Value	Unit
$R_{(0,0-C)}$	Junction to case (AC)	Sxx55R Sxx55N	0.5	$^\circ\text{C}/\text{W}$
		Sxx55W Sxx55M	0.53	
$R_{(0,0-A)}$	Junction to ambient	Sxx55R	40	$^\circ\text{C}/\text{W}$

Note: xx = voltage

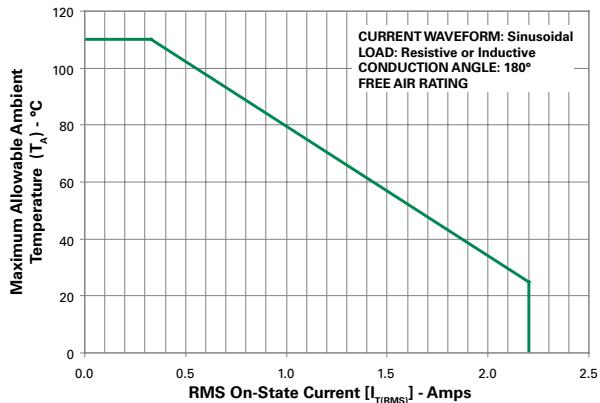
**Figure 1: Normalized DC Gate Trigger Current vs. Junction Temperature**

**Figure 2: Normalized DC Gate Trigger Voltage vs. Junction Temperature**

**Figure 3: Normalized DC Holding Current vs. Junction Temperature**

**Figure 4: On-State Current vs. On-State Voltage (Typical)**

**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**

**Figure 6: Maximum Allowable Case Temperature vs. RMS On-State Current**


Note: xx = voltage

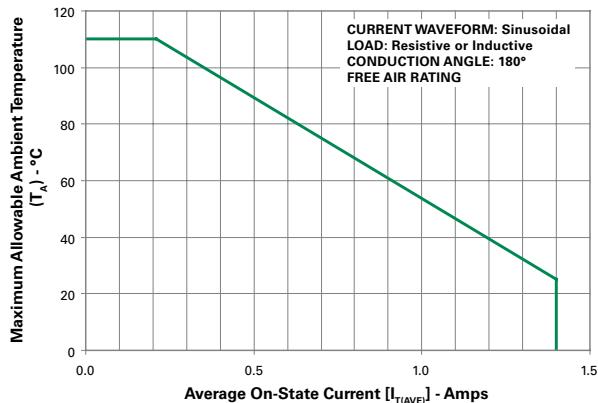
**Figure 7: Maximum Allowable Case Temperature vs. Average On-State Current**



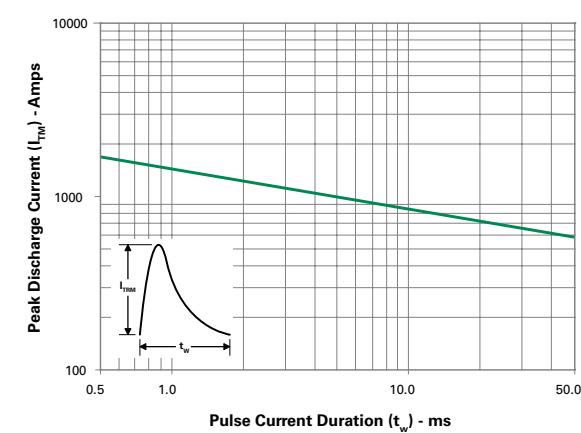
**Figure 8: Maximum Allowable Ambient Temperature vs. RMS On-State Current**



**Figure 9: Maximum Allowable Ambient Temperature vs. Average On-State Current**

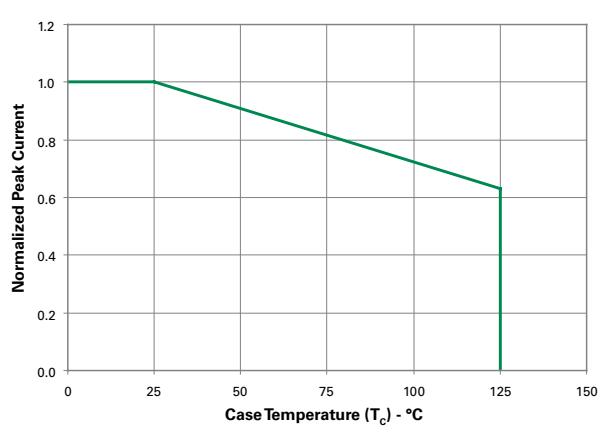


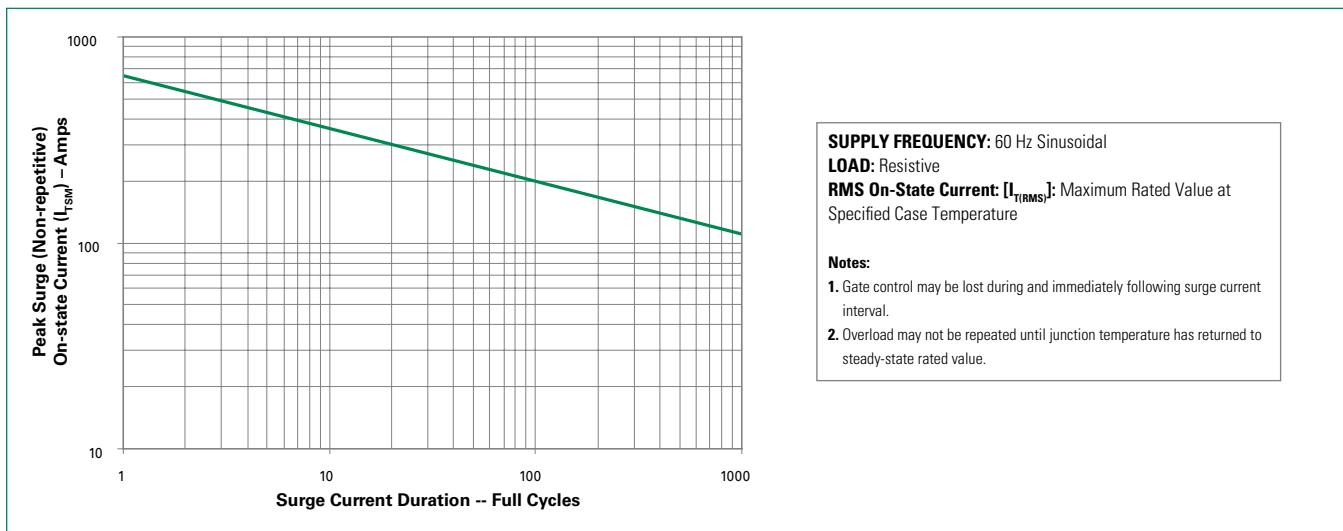
**Figure 10: Peak Capacitor Discharge Current**



**Note:** xx = voltage

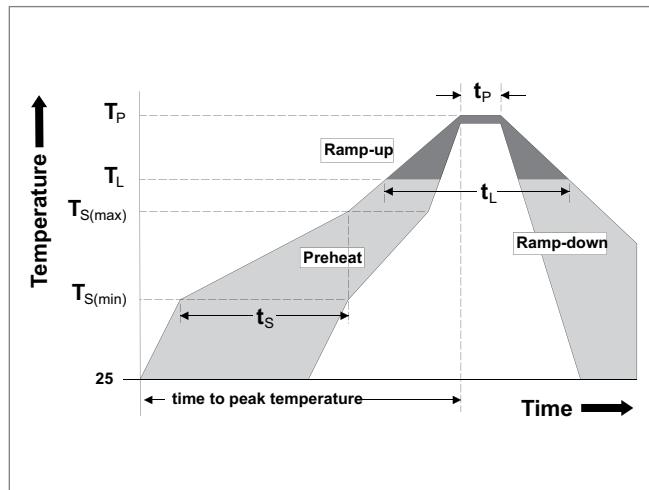
**Figure 11: Peak Capacitor Discharge Current Derating**



**Figure 12: Surge Peak On-State Current vs. Number of Cycles**


### Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	- Temperature Min ( $T_{s(min)}$ )	150°C
	- Temperature Max ( $T_{s(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 – 180 secs
Average ramp up rate (Liquidus Temp) ( $T_L$ ) to peak		5°C/second max
$T_{s(max)}$ to $T_L$ - Ramp-up Rate		5°C/second max
Reflow	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Temperature ( $t_L$ )	60 – 150 seconds
Peak Temperature ( $T_p$ )		260 <sup>+0/-5</sup> °C
Time within 5°C of actual peak Temperature ( $t_p$ )		20 – 40 seconds
Ramp-down Rate		5°C/second max
Time 25°C to peak Temperature ( $T_p$ )		8 minutes Max.
Do not exceed		280°C



### Physical Specifications

<b>Terminal Finish</b>	100% Matte Tin-plated
<b>Body Material</b>	UL recognized epoxy meeting flammability classification 94V-0
<b>Lead Material</b>	Copper Alloy

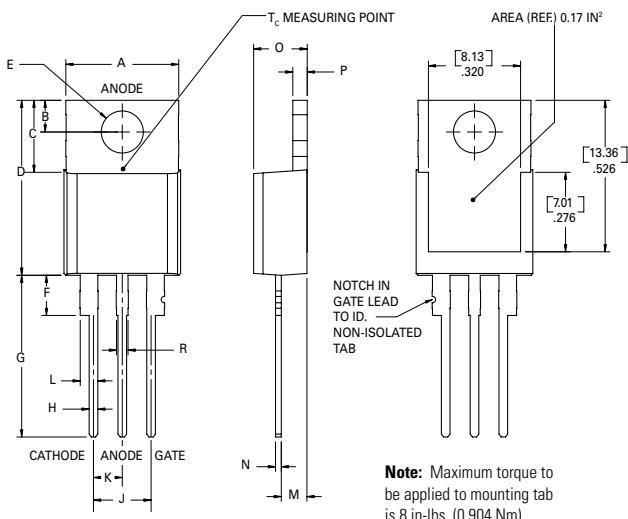
### Design Considerations

Careful selection of the correct device for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the device rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

### Environmental Specifications

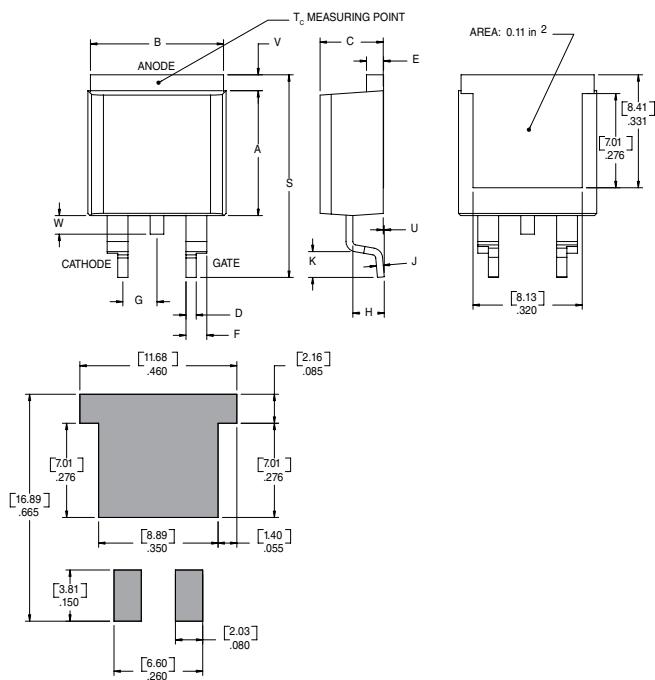
Test	Specifications and Conditions
<b>AC Blocking</b>	MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 125°C for 1008 hours
<b>Temperature Cycling</b>	MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time
<b>Temperature/Humidity</b>	EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC: 85°C; 85% rel humidity
<b>High Temp Storage</b>	MIL-STD-750, M-1031, 1008 hours; 150°C
<b>Low-Temp Storage</b>	1008 hours; -40°C
<b>Resistance to Solder Heat</b>	MIL-STD-750 Method 2031
<b>Solderability</b>	ANSI/J-STD-002, category 3, Test A
<b>Lead Bend</b>	MIL-STD-750, M-2036 Cond E

### Dimensions – TO-220AB (R-Package) – Non-Isolated Mounting Tab Common with Center Lead



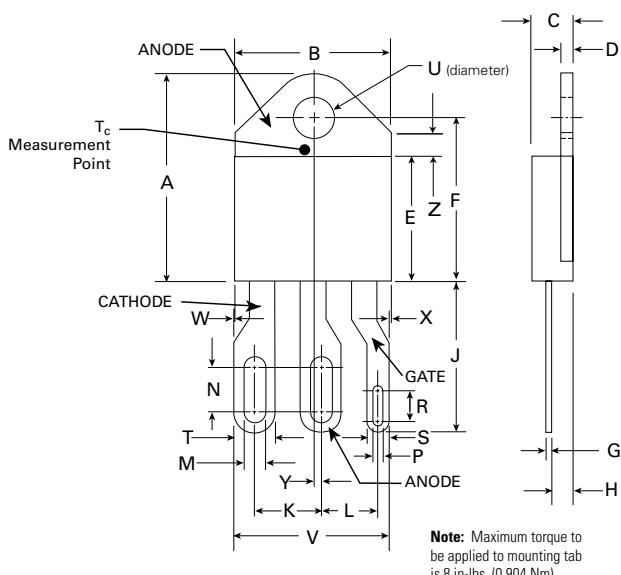
Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.380	0.420	9.65	10.67
B	0.105	0.115	2.67	2.92
C	0.230	0.250	5.84	6.35
D	0.590	0.620	14.99	15.75
E	0.142	0.147	3.61	3.73
F	0.110	0.130	2.79	3.30
G	0.540	0.575	13.72	14.61
H	0.025	0.035	0.64	0.89
J	0.195	0.205	4.95	5.21
K	0.095	0.105	2.41	2.67
L	0.060	0.075	1.52	1.91
M	0.085	0.095	2.16	2.41
N	0.018	0.024	0.46	0.61
O	0.178	0.188	4.52	4.78
P	0.045	0.060	1.14	1.52
R	0.038	0.048	0.97	1.22

### Dimensions – TO-263AB (N-package) – D<sup>2</sup>-Pak Surface Mount



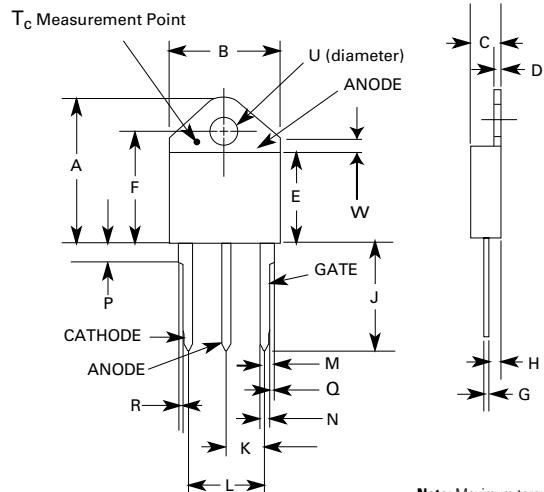
Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.360	0.370	9.14	9.40
B	0.380	0.420	9.65	10.67
C	0.178	0.188	4.52	4.78
D	0.025	0.035	0.63	0.89
E	0.048	0.055	1.22	1.40
F	0.060	0.075	1.52	1.91
G	0.095	0.105	2.41	2.67
H	0.083	0.093	2.11	2.36
J	0.018	0.024	0.46	0.61
K	0.090	0.110	2.29	2.79
S	0.590	0.625	14.99	15.87
V	0.035	0.045	0.89	1.14
U	0.002	0.010	0.05	0.25
W	0.040	0.070	1.02	1.78

### Dimensions – TO-218X (W Package) – Non-Isolated Mounting Tab Common with Center Lead



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
A	0.810	0.835	20.57	21.21
B	0.610	0.630	15.49	16.00
C	0.178	0.188	4.52	4.78
D	0.055	0.070	1.40	1.78
E	0.487	0.497	12.37	12.62
F	0.635	0.655	16.13	16.64
G	0.022	0.029	0.56	0.74
H	0.075	0.095	1.91	2.41
J	0.575	0.625	14.61	15.88
K	0.256	0.264	6.50	6.71
L	0.220	0.228	5.58	5.79
M	0.080	0.088	2.03	2.24
N	0.169	0.177	4.29	4.49
P	0.034	0.042	0.86	1.07
R	0.113	0.121	2.87	3.07
S	0.086	0.096	2.18	2.44
T	0.156	0.166	3.96	4.22
U	0.164	0.165	4.10	4.20
V	0.603	0.618	15.31	15.70
W	0.000	0.005	0.00	0.13
X	0.003	0.012	0.07	0.30
Y	0.028	0.032	0.71	0.81
Z	0.085	0.095	2.17	2.42

### Dimensions – TO-218AC (M Package) – Non-isolated Mounting Tab Common with Center Lead



Dimension	Inches		Millimeters	
	Min	Max	Min	Max
<b>A</b>	0.810	0.835	20.57	21.21
<b>B</b>	0.610	0.630	15.49	16.00
<b>C</b>	0.178	0.188	4.52	4.78
<b>D</b>	0.055	0.070	1.40	1.78
<b>E</b>	0.487	0.497	12.37	12.62
<b>F</b>	0.635	0.655	16.13	16.64
<b>G</b>	0.022	0.029	0.56	0.74
<b>H</b>	0.075	0.095	1.91	2.41
<b>J</b>	0.575	0.625	14.61	15.88
<b>K</b>	0.211	0.219	5.36	5.56
<b>L</b>	0.422	0.437	10.72	11.10
<b>M</b>	0.058	0.068	1.47	1.73
<b>N</b>	0.045	0.055	1.14	1.40
<b>P</b>	0.095	0.115	2.41	2.92
<b>Q</b>	0.008	0.016	0.20	0.41
<b>R</b>	0.008	0.016	0.20	0.41
<b>U</b>	0.164	0.165	4.10	4.20
<b>W</b>	0.085	0.095	2.17	2.42

### Product Selector

Part Number	Voltage				Gate Sensitivity	Type	Package
	400V	600V	800V	1000V			
Sxx55R	X	X	X	X	40mA	Standard SCR	TO-220R
Sxx55N	X	X	X	X	40mA	Standard SCR	TO-263
Sxx55W	X	X	X		40mA	Standard SCR	TO-218X
Sxx55M	X	X	X	X	40mA	Standard SCR	TO-218AC

**Note:** xx = Voltage

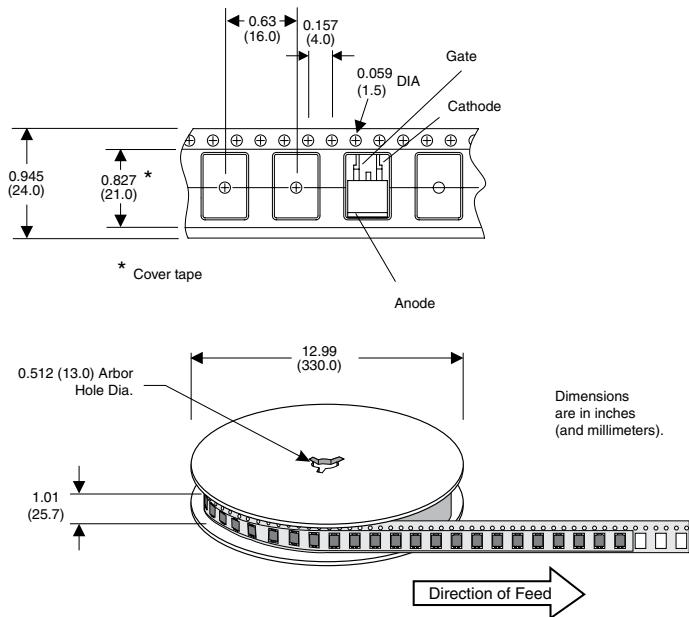
### Packing Options

Part Number	Marking	Weight	Packing Mode	Base Quantity
Sxx55RTP	Sxx55R	2.2g	Tube	1000 (50 per tube)
Sxx55NTP	Sxx55N	1.6g	Tube	1000 (50 per tube)
Sxx55NRP	Sxx55N	1.6g	Embossed Carrier	500
Sxx55WTP	Sxx55W	5.23g	Tube	250 (25 per tube)
Sxx55MTP	Sxx55M	4.40g	Tube	250 (25 per tube)

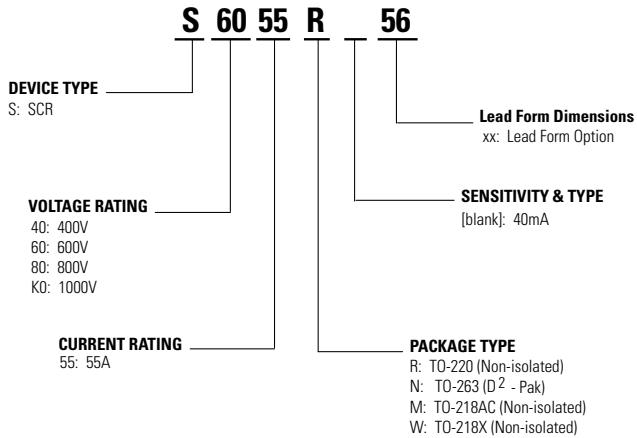
**Note:** xx = Voltage

### TO-263 Embossed Carrier Reel Pack (RP) Specification

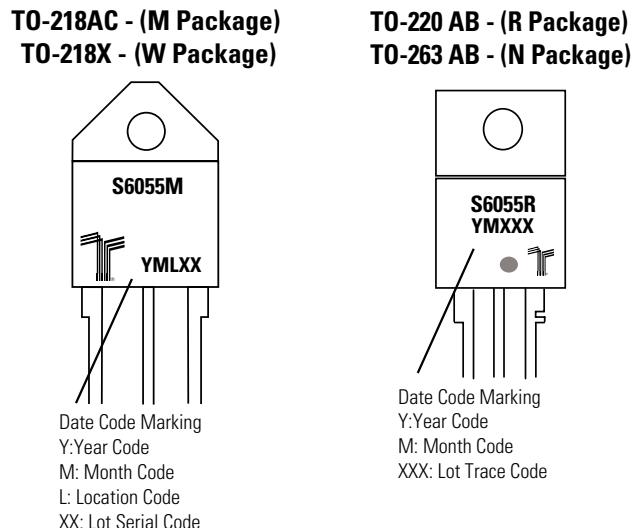
Meets all EIA-481-2 Standards



### Part Numbering System



### Part Marking System



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Revised: B0.12/10/20